Merchant & Gould

An Intellectual Property Law Firm

OFFICIAL

RECEIVED CENTRAL FAX CENTER

MAY 18 2004

3200 IDS Center 80 South Eighth Street Minneapolis, Minnesota 55402-2215 USA та, 612.332.5300 FAX 612.332.9081 www.merchantgould.com

A Professional Corporation

Fax Transmission

TO:

Commissioner for Patents

Attn: Examiner PATEL

Patent Examining Corps

Facsimile Center

Washington, D.C. 20231

FROM:

Douglas P. Mueller

OUR REF:

10873.644US01

TELEPHONE:

612.371.5237

Total pages, including cover letter:

PTO FAX NUMBER 1-703-872-9306

If you do NOT receive all of the pages, please telephone us at 612.336.4638, or fax us at 612.332.9081.

Title of OFFICIAL Document Transmitted:

Attached is a revised version of March 22.

2004 Response to Restriction

Requirement, updated for changes in PTO

format requirements

Applicant:

<u>KUSUMOTO</u>

Serial No.:

09/773,502

Filed:

02/02/01

Group Art Unit: 2829

Our Ref. No.:

10873.644US01

I hereby certify that this paper is being transmitted by facsimile to the U.S. Patent and Trademark Office on the date shown below.

May 18, 2004

S/N 09/773,502

**PATENT** 

## Amendments to the Claims:

This listing of claims will replace all prior versions and listings of claims in the application.

## Listing of Claims:

Claims 1-66 are canceled.

- 67. (Withdrawn) A semiconductor device having a semiconductor integrated circuit, the semiconductor device comprising:
- a plurality of leads for supplying the semiconductor device with a first power source from an outside;
- a first internal power source line for supplying an internal circuit of the semiconductor integrated circuit with the first power source; and
- a first plurality of internal terminals for supplying the first internal power source line with the first power source from the plurality of leads; wherein all of the first plurality of internal terminals are connected to the first internal power source line via a first switching portion.
- 68. (Currently amended) The A semiconductor device according to claim 67, further comprising another internal terminal that is connected directly to the first internal power source line not via the first switching portion. having a semiconductor integrated circuit, the semiconductor device comprising:
- a plurality of leads for supplying the semiconductor device with a first power source from an outside:
- a first internal power source line for supplying an internal circuit of the semiconductor integrated circuit with the first power source; and

S/N 09/773,502

PATENT

a first plurality of internal terminals for supplying the first internal power source line with
s and some from the plurality of leads;
leaving and of the first plurality of internal terminals is connected directly to the internal
internal power source line, and others thereof are connected to the first internal power source line
via a first switching portion.
69. (Withdrawn) The semiconductor device according to claim 67, comprising:
69. (Withdrawn) The semiconductor device according to a second plurality of leads for supplying the semiconductor device with a second power
source from the outside;
a second internal power source line for supplying the internal circuit with the second
power source; and a second plurality of internal terminals for supplying the second internal power source
line with the second power source from the second plurality of leads;
wherein all of the second plurality of internal terminals are connected to the second
internal power source line via a second switching portion.
70. (Currently amended) The semiconductor device according to claim 69 68, further
comprising another internal terminal that is connected directly to the second internal power
line not the a spatching portion.
a second plurality of leads for supplying the semiconductor device with a second power
source from an outside.
a second internal power source line for supplying the internal circuit of the
and and actor integrated circuit with the second power source; and
a second plurality of internal terminals for supplying the second internal power source
and a second plurality of leads:

S/N 09/773,502

PATENT

wherein one of the second plurality of internal terminals is connected directly to the second internal power source line, and others thereof are connected to the second internal power source line via a second switching portion.

- 71. (Withdrawn) The semiconductor device according to claim 69, further comprising a third switching portion provided between the first and second internal power source lines.
- 72. (Withdrawn) The semiconductor device according to claim 69, further comprising a current detecting circuit provided between the first and second internal power source lines.
- 73. (Currently amended) The semiconductor device according to claim 67 68, wherein the internal circuit is a group of digital circuits.
- 74. (Currently amended) The semiconductor device according to claim 67 68, wherein the first switching portion comprises a plurality of switching elements, and each of the first plurality of internal terminals is connected to the first internal power source line via a different switching element of the plurality of switching elements.